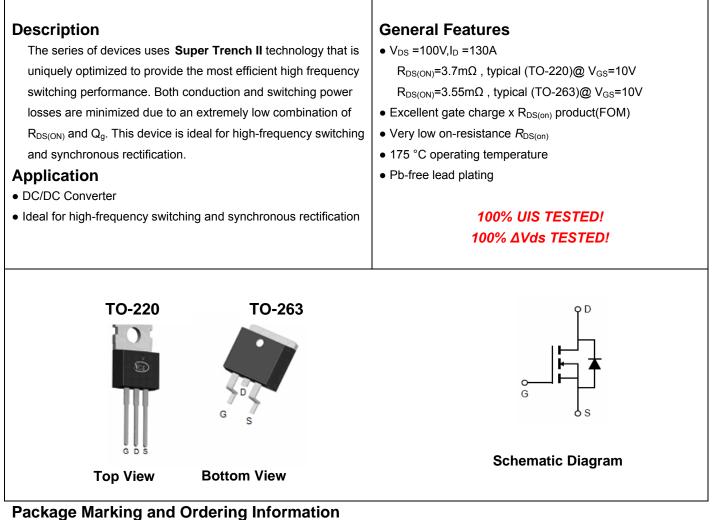


### NCE N-Channel Super Trench II Power MOSFET



# Device MarkingDeviceDevice PackageReel SizeTape widthQuantityNCEP040N10NCEP040N10TO-220-3L---NCEP040N10DNCEP040N10DTO-263-2L---

### Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	100	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι <sub>D</sub>	130	А
Drain Current-Continuous(T <sub>C</sub> =100℃)	I <sub>D</sub> (100℃)	100	А
Pulsed Drain Current <sup>(Note 1)</sup>	I <sub>DM</sub>	520	А
Maximum Power Dissipation	PD	210	W
Derating factor		1.4	W/°C
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	750	mJ
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 175	°C



### **Thermal Characteristic**

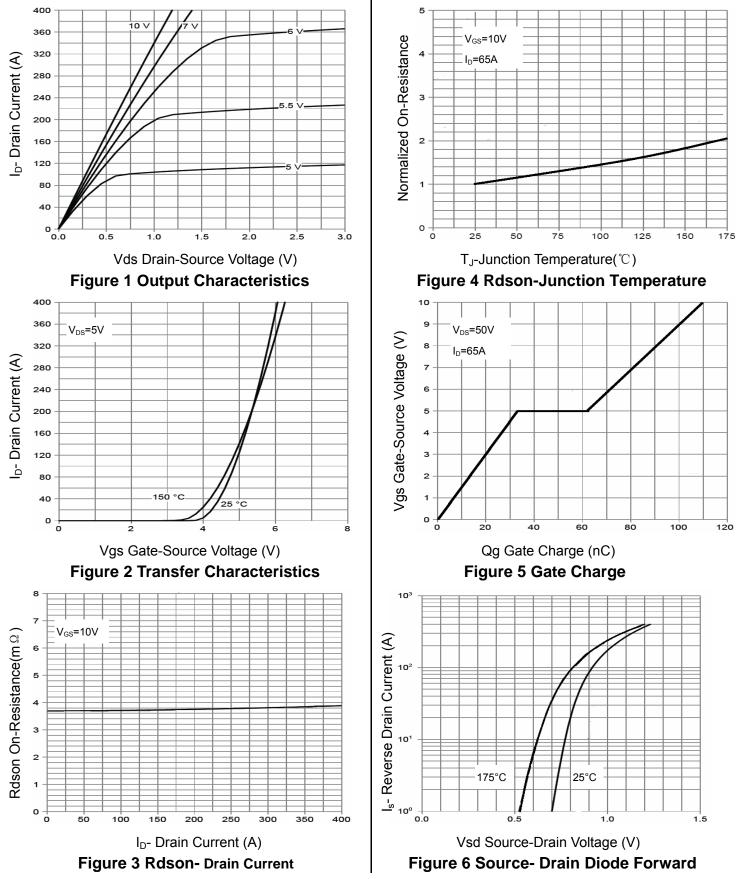
Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>			0.71		°C/W		
Electrical Characteristics (Tc=	=25℃unless	otherwise note	ed)				
Parameter	Symbol	Condition		Min	Тур	Max	Unit
Off Characteristics							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA		100		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V		-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V		-	-	±100	nA
On Characteristics (Note 3)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =28	50µA	2	3	4	V
Drain-Source On-State Resistance	В		TO-220	-	3.7	4.0	mΩ
Dian-Source On-State Resistance	n-Source On-State Resistance $R_{DS(ON)}$ $V_{GS}$ =10V, $I_D$ =65A TC	TO-263		3.55	4.0	mΩ	
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =65A			130	-	S
Dynamic Characteristics (Note4)							
Input Capacitance	C <sub>lss</sub>	- V <sub>DS</sub> =50V,V <sub>GS</sub> =0V, - F=1.0MHz		-	6300	-	PF
Output Capacitance	C <sub>oss</sub>			-	560	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>			-	40	-	PF
Switching Characteristics (Note 4)							
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =50V,I <sub>D</sub> =65A,		-	23	-	nS
Turn-on Rise Time	tr			-	15	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	V <sub>GS</sub> =10V,R <sub>G</sub> =	=3Ω	-	48	-	nS
Turn-Off Fall Time	t <sub>f</sub>	1		-	16	-	nS
Total Gate Charge	Qg	- V <sub>DS</sub> =50V,I <sub>D</sub> =65A, - V <sub>GS</sub> =10V		-	110	-	nC
Gate-Source Charge	Q <sub>gs</sub>			-	33		nC
Gate-Drain Charge	Q <sub>gd</sub>			-	30		nC
Drain-Source Diode Characteristics							
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =65A		-		1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>			-	-	130	А
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C, I_F = 65A$ di/dt = 100A/µs <sup>(Note3)</sup>		-	70	-	nS
Reverse Recovery Charge	Qrr			-	117	-	nC

#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t  $\leq$  10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^\circ C$  ,V\_DD=50V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$

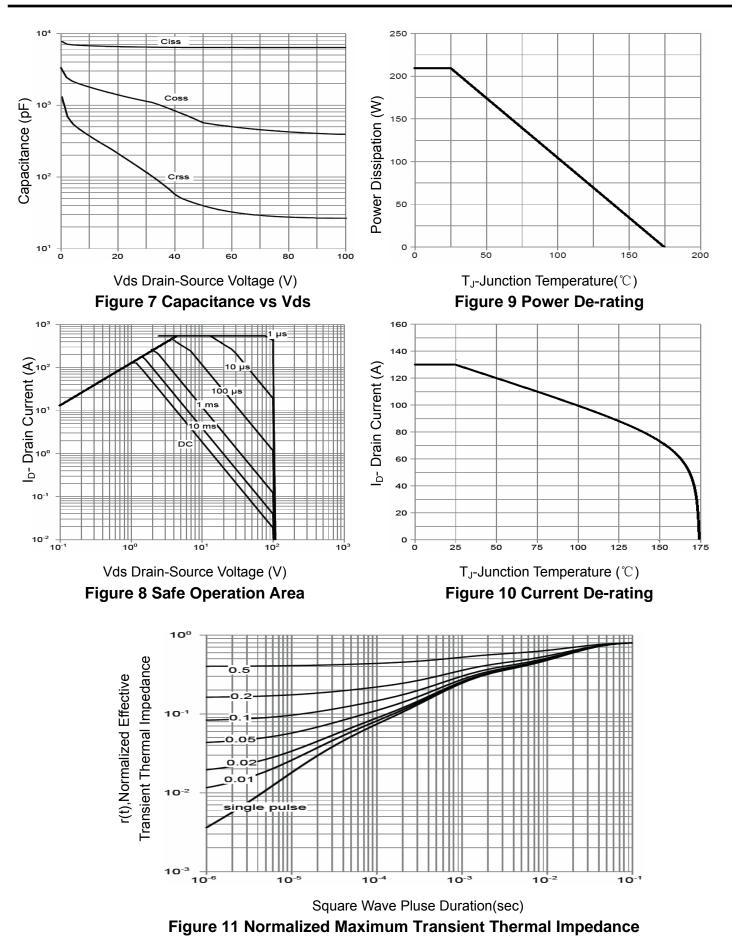


### **Typical Electrical and Thermal Characteristics**



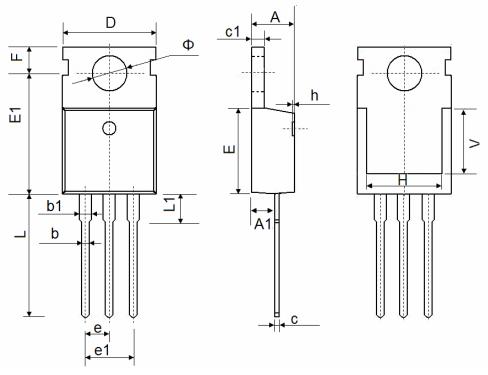


# NCEP040N10,NCEP040N10D





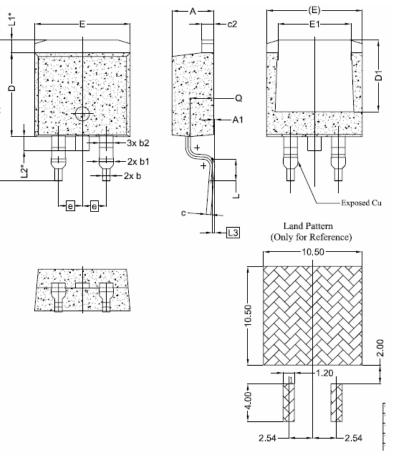
### **TO-220-3L Package Information**



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	6.900 REF.		0.276 REF.		
Φ	3.400	3.800	0.134	0.150	



## **TO-263-2L Package Information**



SYMBOL	DIMENSIONS			
	MIN.	NOM.	MAX.	
А	4.24	4.44	4.64	
A1	0.00	0.10	0.25	
b	0.70	0.80	0.90	
b1	1.20	1.55	1.75	
b2	1,20	1,45	1,70	
с	0.40	0.50	0.60	
c2	1,15	1,27	1,40	
D	8.82	8.92	9.02	
D1	6.86	7.65	_	
E	9.96	10.16	10.36	
E1	6.89	7.77	7.89	
е	2.54 BSC			
н	14,61	15,00	15,88	
L	1.78	2.32	2.79	
L1	1.36 REF.			
L2	1.50 REF.			
L3	0.25 BSC			
Q	2.30	2.48	2.70	



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